NSN 5962-01-199-2578

Memory Microcircuit - Page 1 of 1

Fiig: A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-199-2578 **Features Provided:** Monolithic and burn in and programmable **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 82577-3567351-3 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No